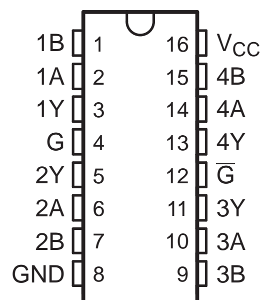
LOW-VOLTAGE HIGH-SPEED QUADRUPLE DIFFERENTIAL LINE RECEIVER WITH ±15-kV IEC ESD PROTECTION

Check for Samples: AM26LV32E

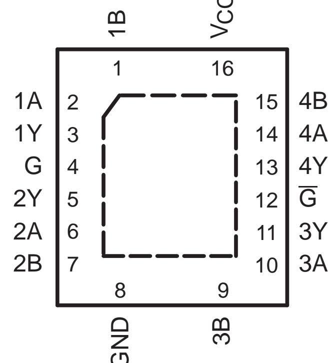
FEATURES

- **Meets or Exceeds Standard TIA/EIA-422-B and ITU Recommendation V.11**
- **Operates From a Single 3.3-V Power Supply**
- **ESD Protection for RS422 Bus Pins**
  - **±15-kV Human-Body Model (HBM)**
  - **±8-kV IEC61000-4-2, Contact Discharge**
  - **±15-kV IEC61000-4-2, Air-Gap Discharge**
- **Switching Rates up to 32 MHz**
- **Low Power Dissipation: 27 mW Typ**
- **Open-Circuit, Short-Circuit, and Terminated Fail-Safe**
- **±7-V Common-Mode Input Voltage Range With ±200-mV Sensitivity**
- **Accepts 5-V Logic Inputs With 3.3-V Supply (Enable Inputs)**
- **Input Hysteresis: 35 mV Typ**
- **Pin-to-Pin Compatible With AM26C32, AM26LS32**
- **I_{off} Supports Partial-Power-Down Mode Operation**
- **Package Options: SOP, SOIC, TSSOP, QFN**

D, NS, OR PW PACKAGE
(TOP VIEW)



RGY PACKAGE
(TOP VIEW)



DESCRIPTION/ORDERING INFORMATION

The AM26LV32E consists of quadruple differential line receivers with 3-state outputs. These differential receivers have ±15-kV ESD (HBM and IEC61000-4-2, Air-Gap Discharge) and ±8-kV ESD (IEC61000-4-2, Contact Discharge) protection for RS422 bus pins.

This device is designed to meet TIA/EIA-422-B and ITU recommendation V.11 drivers with reduced supply voltage. The device is optimized for balanced bus transmission at switching rates up to 32 MHz. The 3-state outputs permit connection directly to a bus-organized system.

The AM26LV32E has an internal fail-safe circuitry that prevents the device from putting an unknown voltage signal at the receiver outputs. In the open fail-safe, shorted fail-safe, and terminated fail-safe, a high state is produced at the respective output.

This device is supported for partial-power-down applications using I_{off}. I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The AM26LV32EI is characterized for operation from –40°C to 85°C.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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Table 1. ORDERING INFORMATION

T_A	PACKAGE(1) (2)		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	SOIC – D	Tape and reel	AM26LV32EIDR	AM26LV32EI
	SOP – NS	Tape and reel	AM26LV32EINSR	26LV32EI
	TSSOP – PW	Tape and reel	AM26LV32EIPWR	SB32
	QFN – RGY	Tape and reel	AM26LV32EIRGYR	SB32

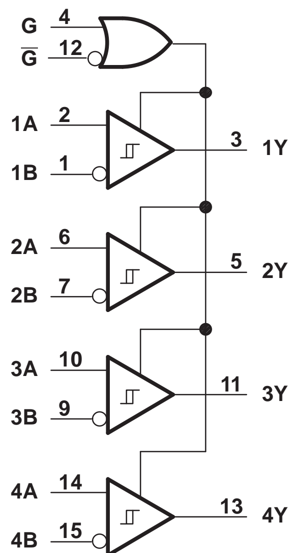
(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

FUNCTION TABLE(1)
(each receiver)

DIFFERENTIAL INPUT	ENABLES		OUTPUT
	G	$\overline{G}$	
$V_{ID} \geq 0.2$ V	H	X	H
	X	L	H
-0.2 V < V_{ID} < 0.2 V	H	X	?
	X	L	?
$V_{ID} \leq -0.2$ V	H	X	L
	X	L	L
Open, shorted, or terminated	H	X	H
	X	L	H
X	L	H	Z

(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off), ? = indeterminate

LOGIC DIAGRAM (POSITIVE LOGIC)



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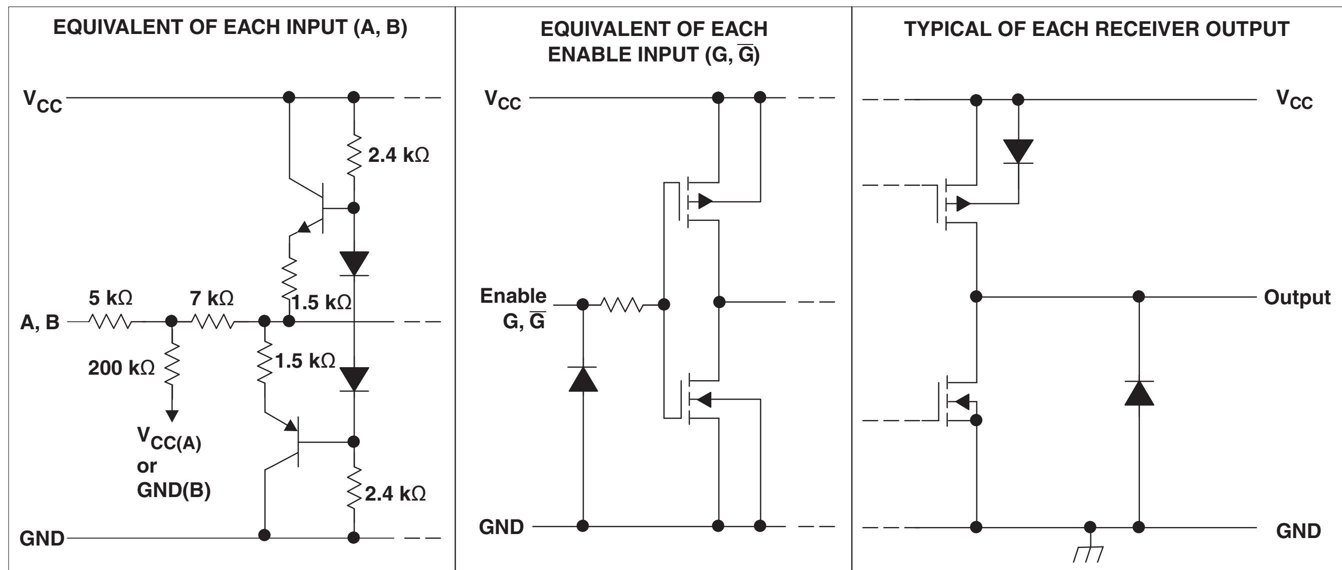
SCHEMATIC



All resistor values are nominal.

ABSOLUTE MAXIMUM RATINGS(1) (2)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range(3)		–0.5	6	V
V_I	Input voltage range	A or B inputs	–14	14	V
		Enable Inputs	–0.5	6	V
V_{ID}	Differential input voltage(4)		–14	14	V
V_O	Output voltage range		–0.5	6	V
I_{IK}	Input clamp current range	$V_I < 0$		–20	mA
I_{OK}	Output clamp current range	$V_O < 0$		–20	mA
I_O	Maximum output current			±20	mA
T_J	Operating virtual junction temperature			150	°C
θ_{JA}	Package thermal impedance(5) (6)	D package		73	°C/W
		NS package		64	
		PW package		108	
		RGY package		39	
T_A	Operating free-air temperature range		–40	85	°C
T_{stg}	Storage temperature range		–65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) This device is designed to meet TIA/EIA-422-B and ITU.
(3) All voltage values except differential input voltage are with respect to the network GND.
(4) Differential input voltage is measured at the noninverting input with respect to the corresponding inverting input.
(5) Maximum power dissipation is a function of $T_{J(max)}$, θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_{J(max)} – T_A)/\theta_{JA}$. Selecting the maximum of 150°C can affect reliability.
(6) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS

		MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage	3	3.3	3.6	V
V_{IH}	Enable high-level input voltage	2		5.5	V
V_{IL}	Enable low-level input voltage	0		0.8	V
V_{IC}	Common-mode input voltage	–7		7	V
V_{ID}	Differential input voltage	–7		7	V
I_{OH}	High-level output current			–5	mA
I_{OL}	Low-level output current			5	mA
T_A	Operating free-air temperature	–40		85	°C

ELECTRICAL CHARACTERISTICS

over recommended ranges of common-mode input, supply voltage, and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP[(1)]	MAX	UNIT
V_{IT+}	Positive-going input threshold voltage, differential input					0.2	V
V_{IT-}	Negative-going input threshold voltage, differential input			–0.2			V
V_{hys}	Input hysteresis ($V_{IT+} – V_{IT-}$)				35		mV
V_{IK}	Input clamp voltage, G and $\overline{G}$	I_I = –18 mA				–1.5	V
V_{OH}	High-level output voltage	V_{ID} = 200 mV, I_{OH} = –5 mA		2.4	3.2		V
		V_{ID} = 200 mV, I_{OH} = –100 µA		V_{CC} – 0.1			
V_{OL}	Low-level output voltage	V_{ID} = –200 mV, I_{OL} = 5 mA			0.17	0.5	V
		V_{ID} = –200 mV, I_{OL} = 100 µA				0.1	
I_{OZ}	High-impedance state output current	V_O = V_{CC} or GND				±50	µA
I_{off}	Output current with power off	V_{CC} = 0 V, V_O = 0 or 5.5 V				±100	µA
I_I	Line input current	Other input at 0 V	V_I = 10 V			1.5	mA
			V_I = –10 V			–2.5	
I_I	Enable input current, G and $\overline{G}$	V_I = V_{CC} or GND				±1	µA
r_i	Input resistance	V_{IC} = –7 V to 7 V, Other input at 0 V		4	17		kΩ
I_{CC}	Supply current (total package)	G, $\overline{G}$ = V_{CC} or GND, No load, Line inputs open			8	17	mA
C_{pd}	Power dissipation capacitance[(2)]	One channel			150		pF

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25°C.
(2) C_{pd} determines the no-load dynamic current consumption: $I_S = C_{pd} \times V_{CC} \times f + I_{CC}$

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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
t_{PLH}	Propagation delay time, low- to high-level output	See Figure 1	8	16	26	ns
t_{PHL}	Propagation delay time, high- to low-level output		8	16	26	ns
t_t	Transition time	See Figure 1		5		ns
t_{PZH}	Output-enable time to high level	See Figure 2		17	40	ns
t_{PZL}	Output-enable time to low level	See Figure 3		10	40	ns
t_{PHZ}	Output-disable time from high level	See Figure 2		20	40	ns
t_{PLZ}	Output-disable time from low level	See Figure 3		16	40	ns
$t_{sk(p)}$	Pulse skew	See Figure 1 (2)		4	6	ns
$t_{sk(o)}$	Pulse skew	See Figure 1 (3)		4	6	ns
$t_{sk(pp)}$	Pulse skew (device to device)	See Figure 1 (4)		6	9	ns
$f_{(max)}$	Maximum operating frequency	See Figure 1		32		MHz

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25°C.
(2) $t_{sk(p)}$ is $|t_{pLH} – t_{pHL}|$ of each channel of same device.
(3) $t_{sk(o)}$ is the maximum difference in propagation delay times between any two channels of same device switching in the same direction.
(4) $t_{sk(pp)}$ is the maximum difference in propagation delay times between any two channels of any two devices switching in the same direction.

ESD PROTECTION

PARAMETER	TEST CONDITIONS	TYP	UNIT
Receiver input	HBM	±15	kV
	IEC61000-4-2, Air-Gap Discharge	±15	
	IEC61000-4-2, Contact Discharge	±8	

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PARAMETER MEASUREMENT INFORMATION

A. C_L includes probe and jig capacitance.
B. The input pulse is supplied by a generator having the following characteristics: PRR = 10 MHz, duty cycle = 50%, $t_r = t_f \le 2ns$.
C. To test the active-low enable $\overline{G}$, ground G and apply an inverted waveform $\overline{G}$.

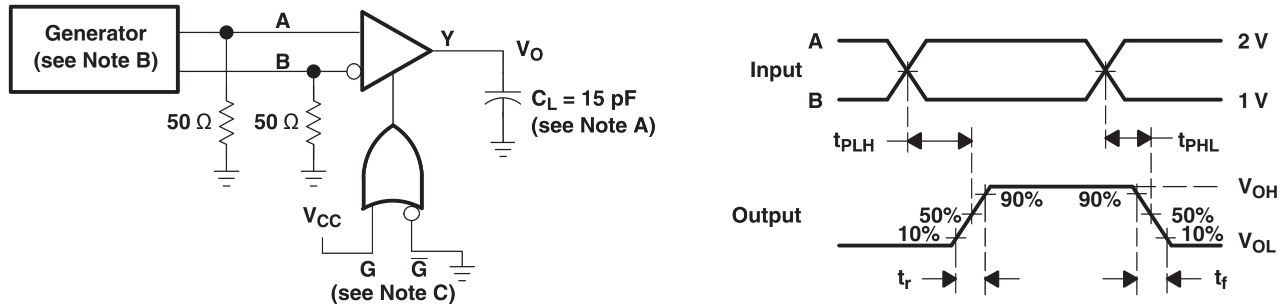

Figure 1. Test Circuit and Voltage Waveforms, t_{PLH} and t_{PHL}

A. C_L includes probe and jig capacitance.
B. The input pulse is supplied by a generator having the following characteristics: PRR = 10 MHz, duty cycle = 50%, $t_r = t_f \le 2ns$.
C. To test the active-low enable $\overline{G}$, ground G and apply an inverted waveform $\overline{G}$.

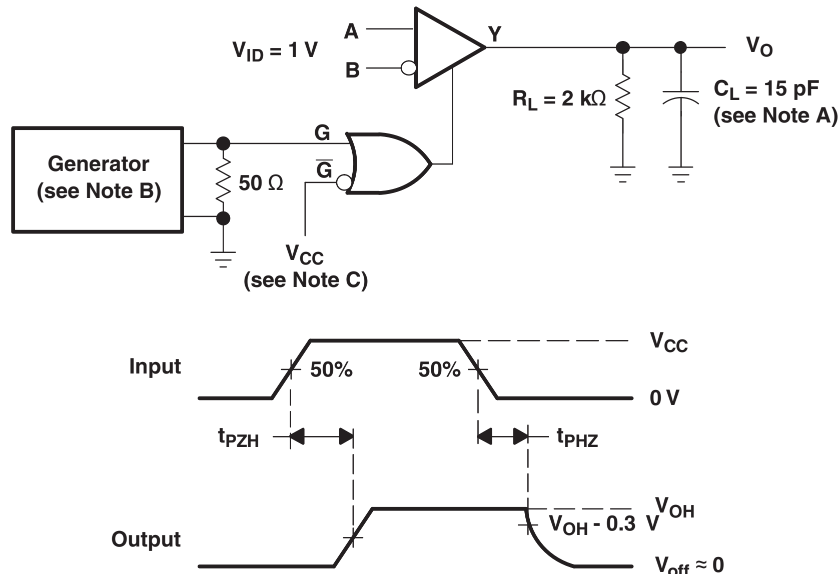

Figure 2. Test Circuit and Voltage Waveforms, t_{PZH} and t_{PHZ}

A. C_L includes probe and jig capacitance.
B. The input pulse is supplied by a generator having the following characteristics: PRR = 10 MHz, duty cycle = 50%, $t_r = t_f \le 2ns$.
C. To test the active-low enable $\overline{G}$, ground G and apply an inverted waveform $\overline{G}$.

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PARAMETER MEASUREMENT INFORMATION (continued)

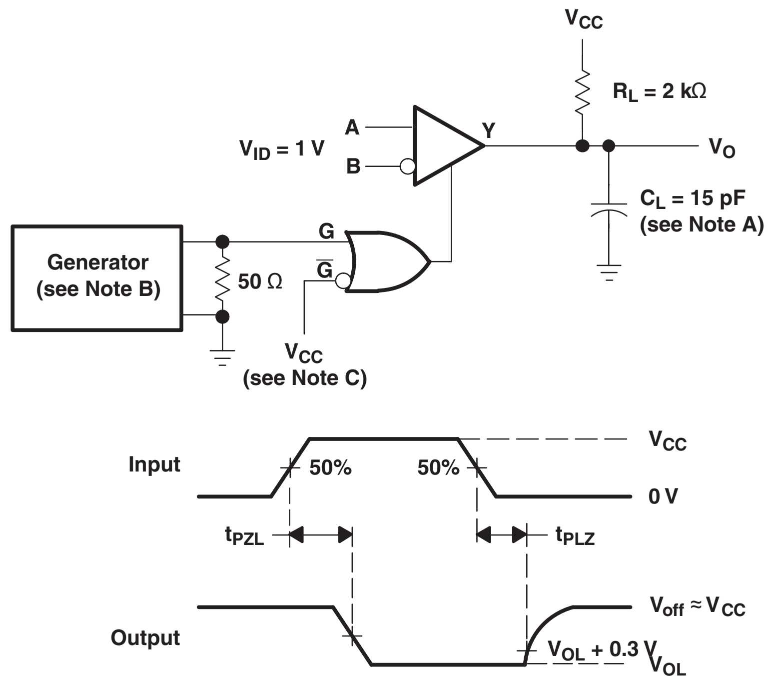

Figure 3. Test Circuit and Voltage Waveforms, t_{PZL} and t_{PLZ}

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
AM26LV32EIDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AM26LV32EI	Samples
AM26LV32EIDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AM26LV32EI	Samples
AM26LV32EINSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26LV32EI	Samples
AM26LV32EINSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26LV32EI	Samples
AM26LV32EIPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	SB32	Samples
AM26LV32EIPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	SB32	Samples
AM26LV32EIRGYR	ACTIVE	VQFN	RGY	16	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SB32	Samples
AM26LV32EIRGYRG4	ACTIVE	VQFN	RGY	16	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SB32	Samples

[1] The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

[2] Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

[3] MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

[4] Only one of markings shown within the brackets will appear on the physical device.

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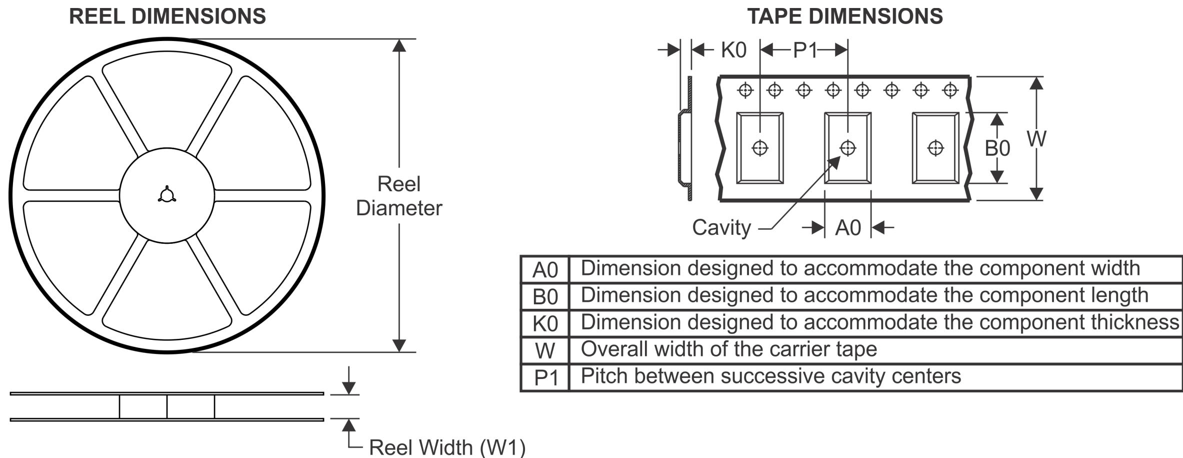
OTHER QUALIFIED VERSIONS OF AM26LV32E :

- Enhanced Product: AM26LV32E-EP

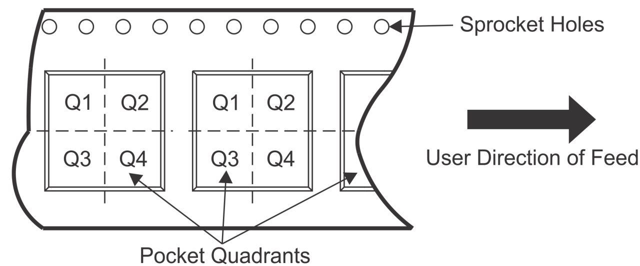
NOTE: Qualified Version Definitions:

- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION



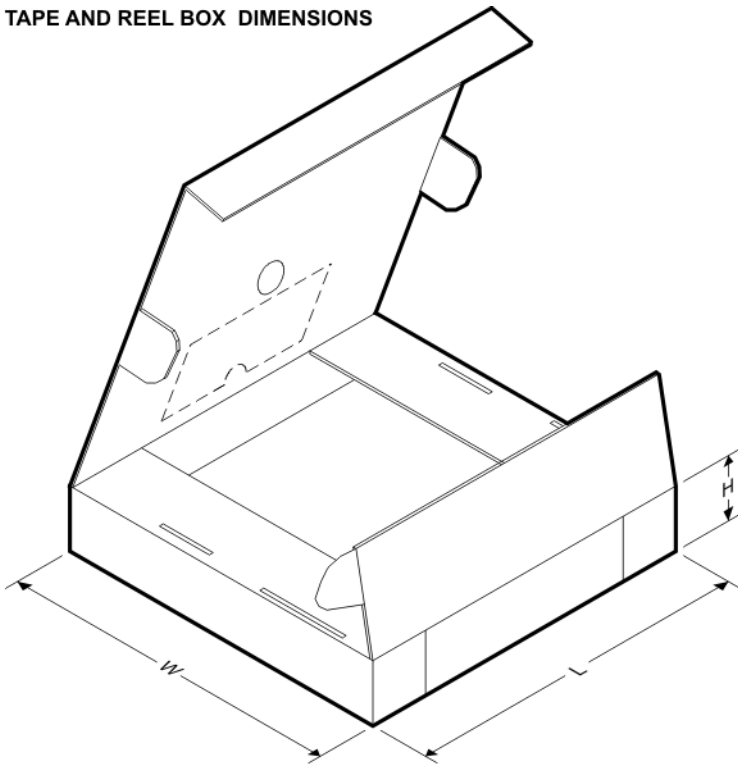
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
AM26LV32EIDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
AM26LV32EIPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
AM26LV32EIRGYR	VQFN	RGY	16	3000	330.0	12.4	3.8	4.3	1.5	8.0	12.0	Q1

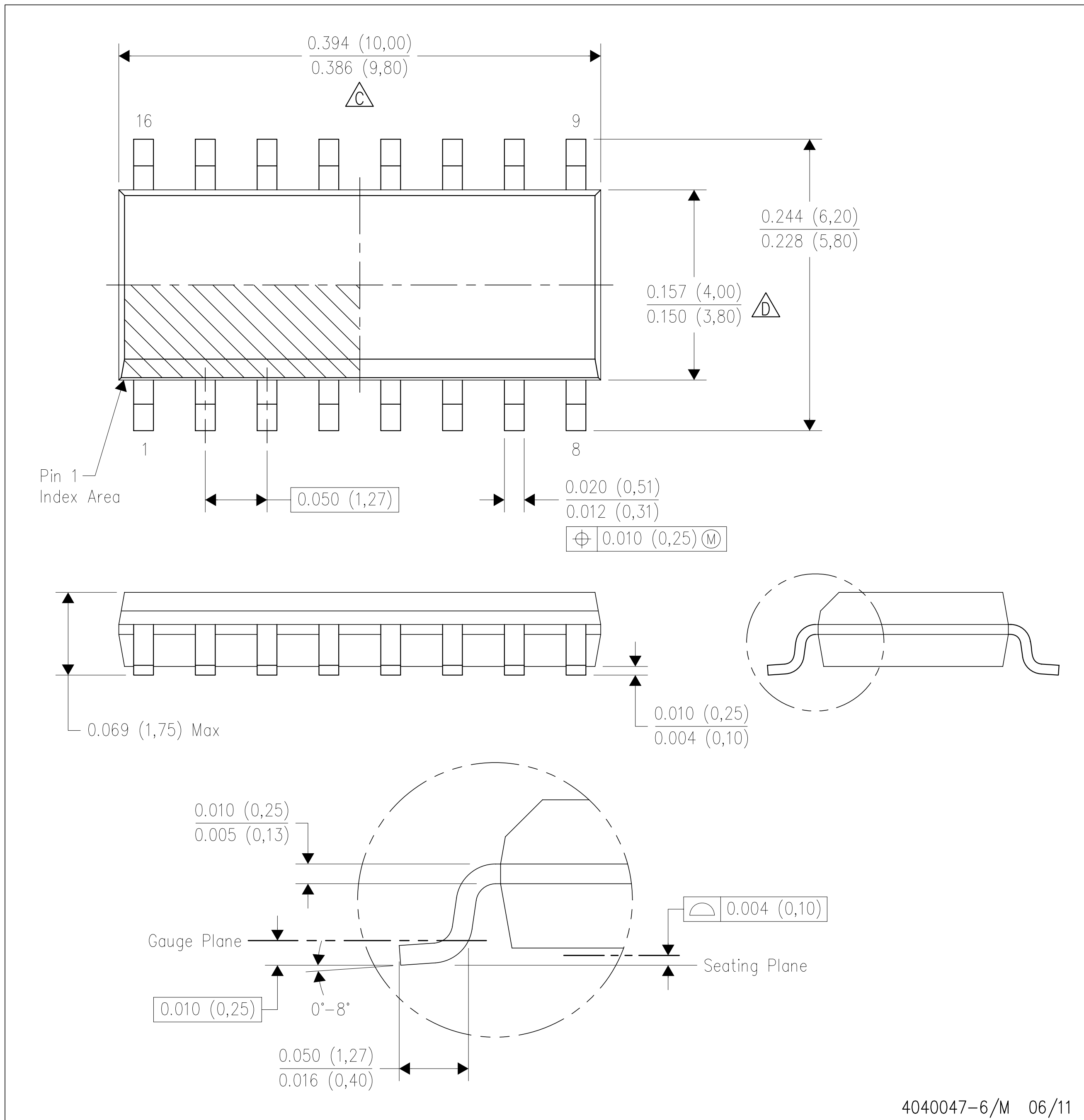
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

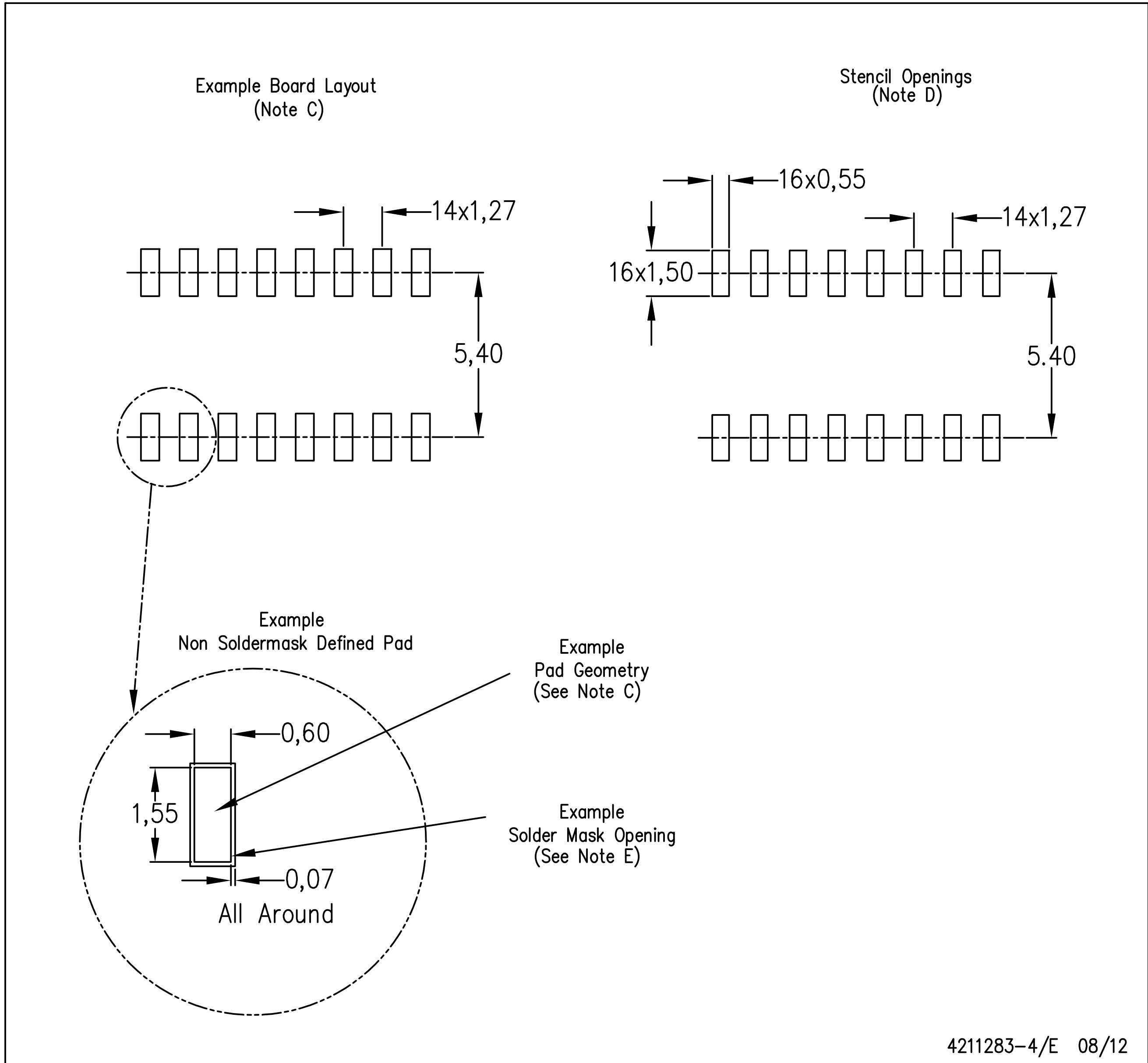
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
AM26LV32EIDR	SOIC	D	16	2500	367.0	367.0	38.0
AM26LV32EIPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
AM26LV32EIRGYR	VQFN	RGY	16	3000	367.0	367.0	35.0

D (R–PDSO–G16) PLASTIC SMALL OUTLINE



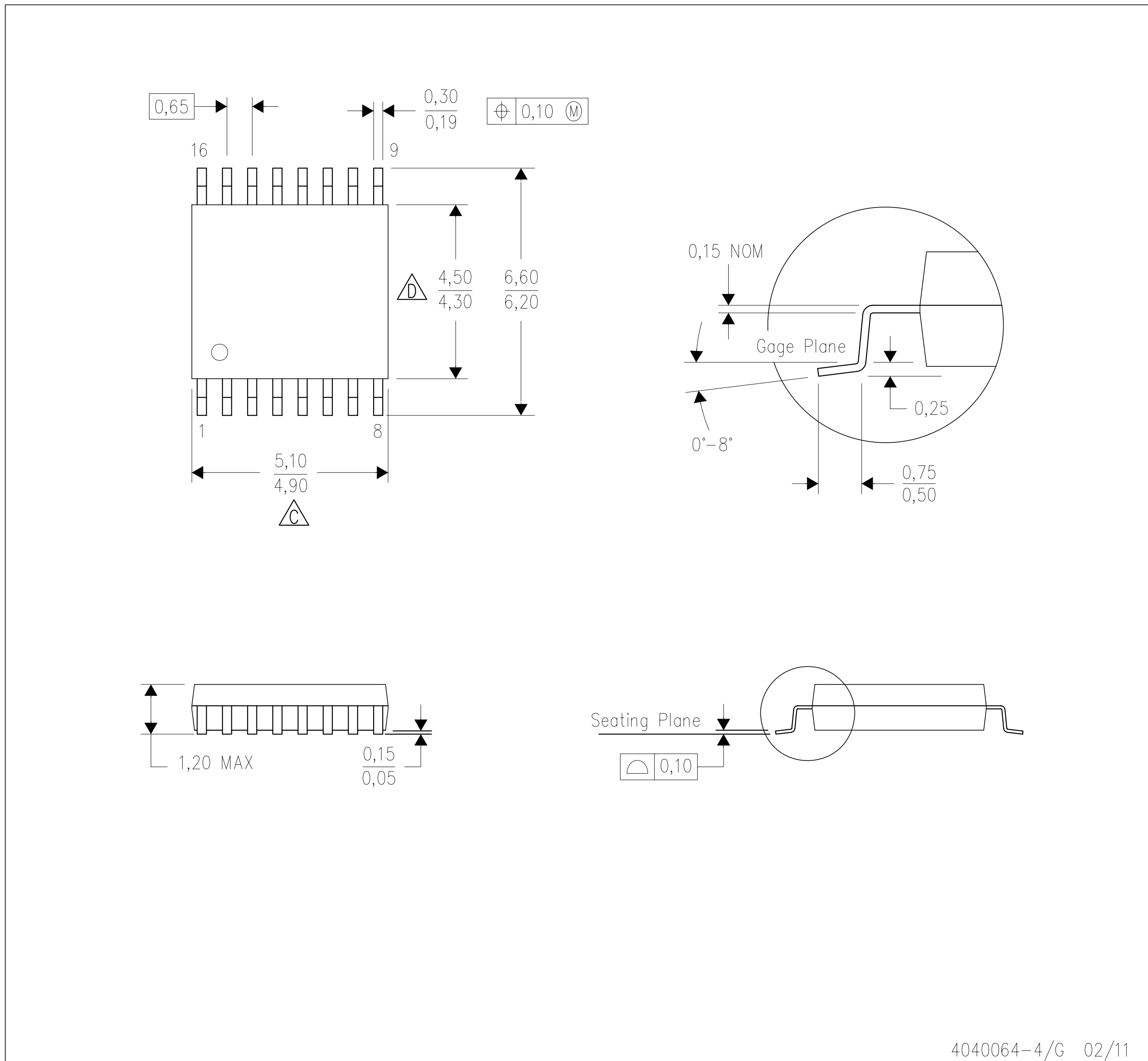
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS-012 variation AC.

D (R-PDSO-G16) PLASTIC SMALL OUTLINE



NOTES:
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PW (R-PDSO-G16) PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.

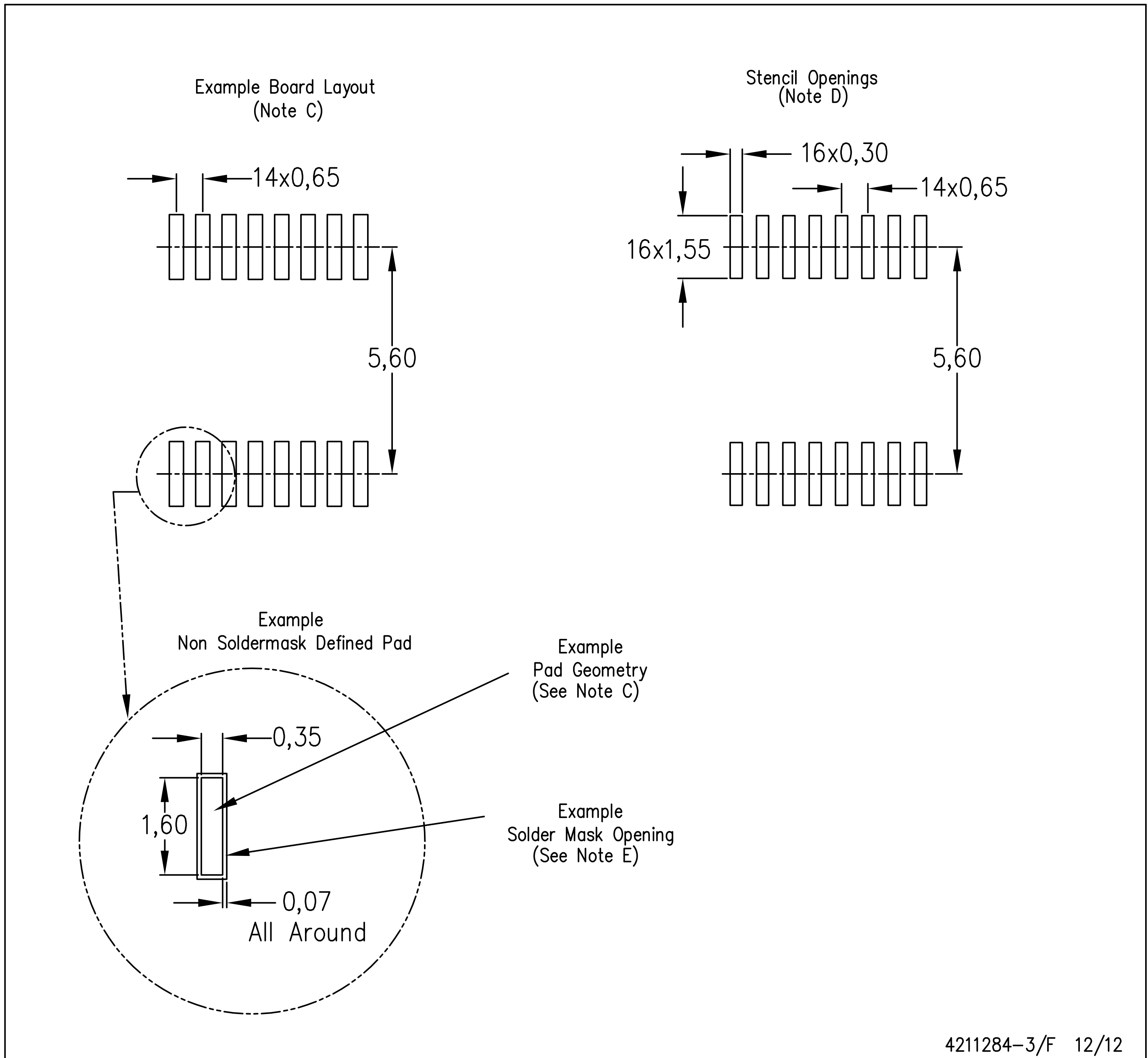
B. This drawing is subject to change without notice.

C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153

PW (R–PDSO–G16) PLASTIC SMALL OUTLINE



NOTES:
- A. All linear dimensions are in millimeters.
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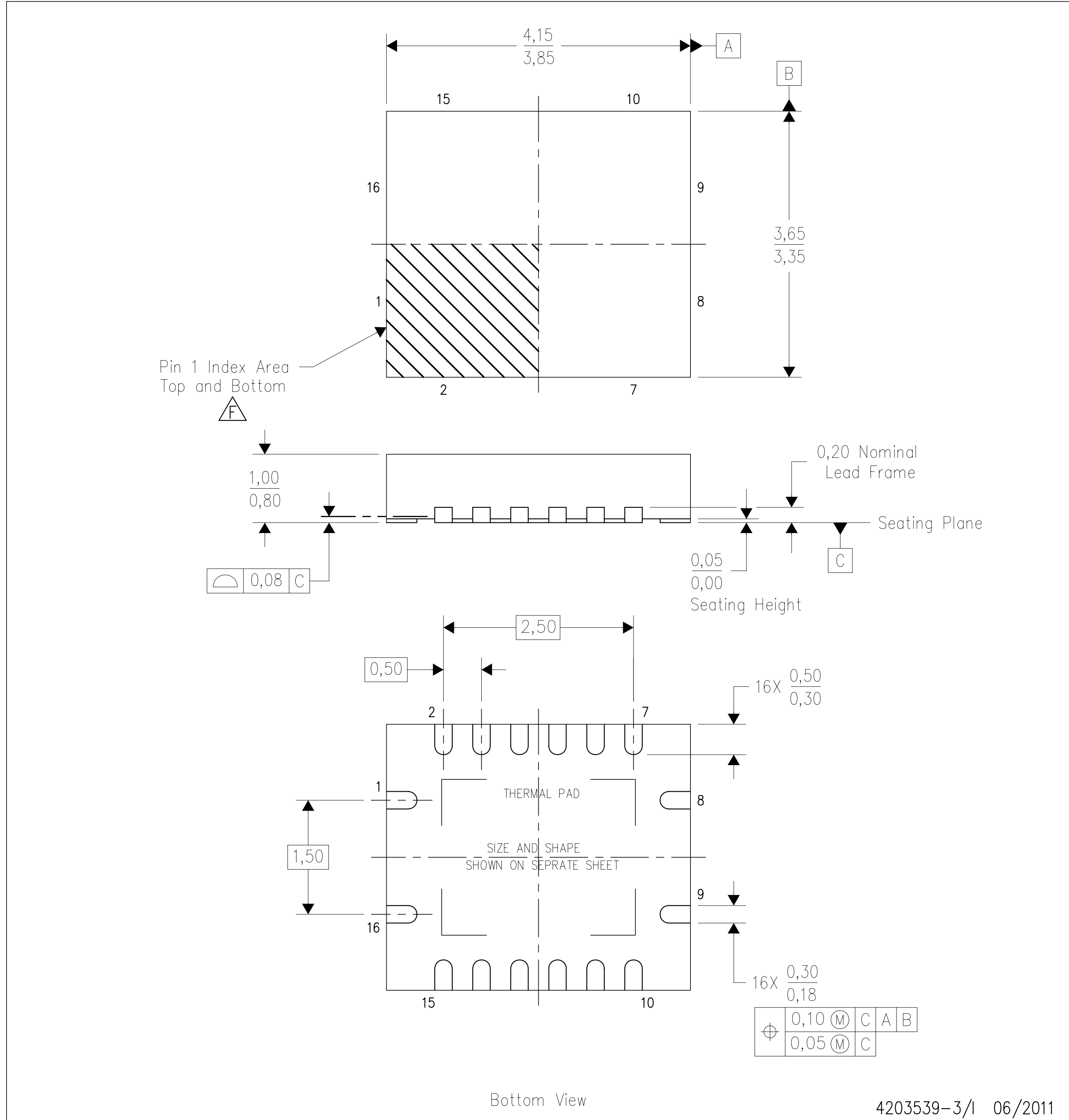
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

RGY (R-PVQFN-N16) PLASTIC QUAD FLATPACK NO-LEAD



NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F. (△) Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.

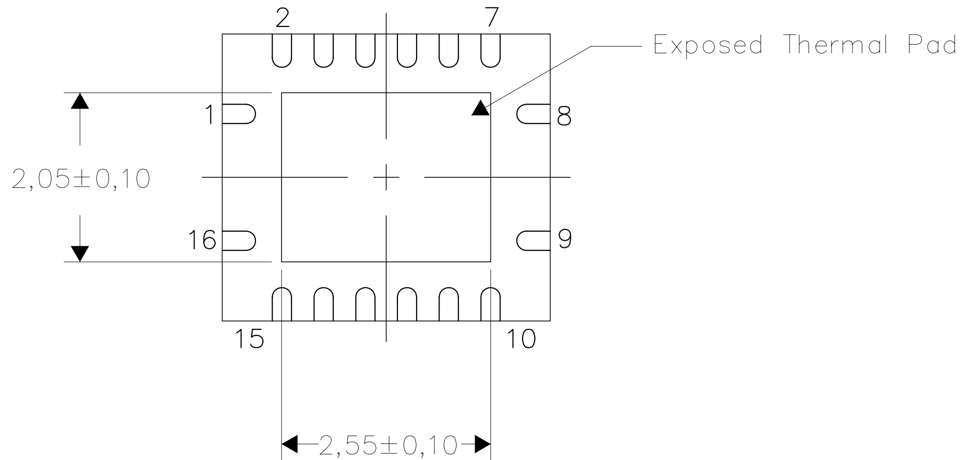
RGY (R–PVQFN–N16) PLASTIC QUAD FLATPACK NO–LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No–Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

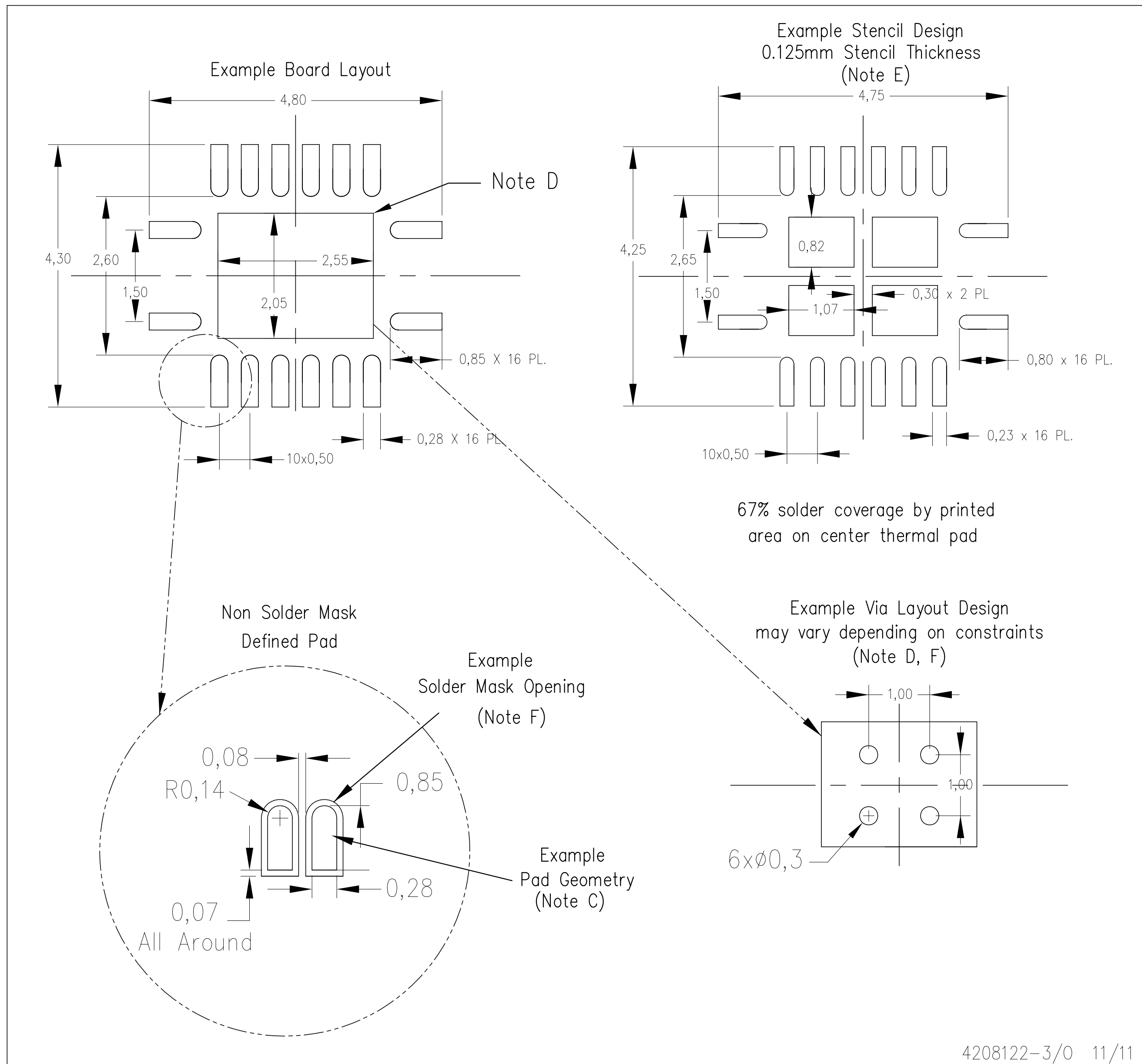


Exposed Thermal Pad Dimensions

4206353–3/O 11/11

NOTE: All linear dimensions are in millimeters

RGY (R-PVQFN-N16) PLASTIC QUAD FLATPACK NO-LEAD



NOTES:

A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Publication IPC-7351 is recommended for alternate designs.

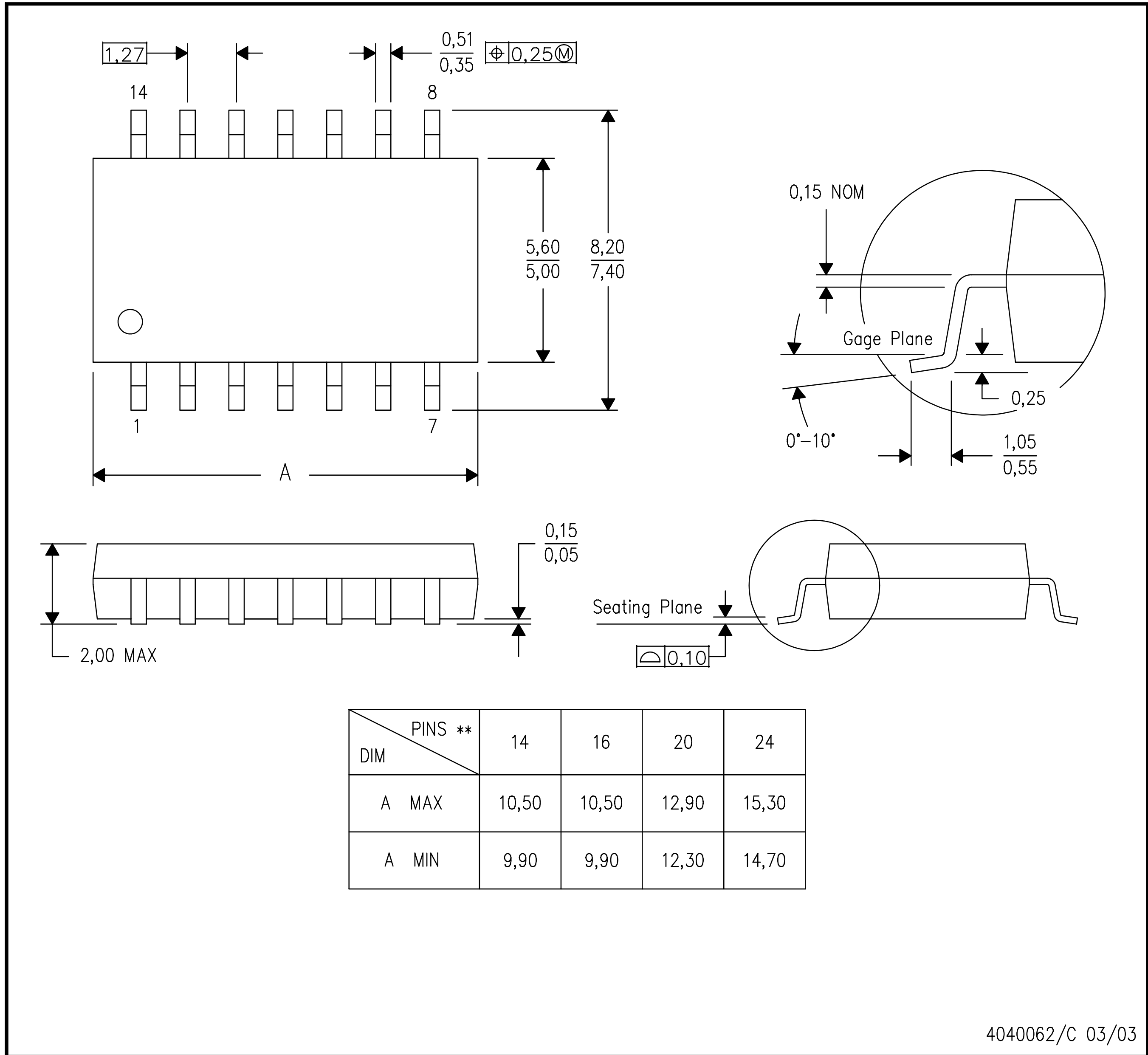
D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>.

E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.

F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.

NS (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14-PINS SHOWN



DIM \ PINS **	14	16	20	24
A MAX	10,50	10,50	12,90	15,30
A MIN	9,90	9,90	12,30	14,70

NOTES:
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

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